Preferred Device

Silicon Controlled Rectifiers

Reverse Blocking Thyristors

Designed for high volume, low cost, industrial and consumer applications such as motor control; process control; temperature, light and speed control.

- Small Size
- Passivated Die for Reliability and Uniformity
- Low Level Triggering and Holding Characteristics
- Available in Surface Mount Lead Form Case 369A
- Device Marking: Device Type, e.g., MCR8DCM, Date Code

Rating	Symbol	Value	Unit	
Peak Repetitive Off–State Voltage ⁽¹⁾ ($T_J = -40$ to 125°C, Sine Wave, 50 to 60 Hz, Gate Open)	^V drm, V _{RRM}		Volts	
MCR8DCM MCR8DCN		600 800		
On–State RMS Current (180° Conduction Angles; T _C = 105°C)	I _{T(RMS)}	8.0	Amps	
Average On–State Current (180° Conduction Angles; T _C = 105°C)	lt(AV)	5.1	Amps	
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, T _J = 125°C)	ITSM	80	Amps	
Circuit Fusing Consideration (t = 8.3 msec)	l ² t	26	A ² sec	
Forward Peak Gate Power (Pulse Width \leq 1.0 μ sec, T _C = 105°C)	PGM	5.0	Watts	
Forward Average Gate Power (t = 8.3 msec, T _C = 105°C)	PG(AV)	0.5	Watts	
Forward Peak Gate Current (Pulse Width \leq 1.0 μ sec, T _C = 105°C)	IGM	2.0	Amps	
Operating Junction Temperature Range	ТJ	-40 to 125	°C	
Storage Temperature Range	T _{stg}	-40 to 150	°C	

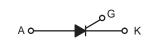
(1) V_{DRM}, V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the device are exceeded.



ON Semiconductor

http://onsemi.com

SCRs 8 AMPERES RMS 600 thru 800 VOLTS





D-PAK

CASE 369A STYLE 4

PIN ASSIGNMENT				
1	Cathode			
2	Anode			
3	Gate			
4	Anode			

ORDERING INFORMATION

Device	Package	Shipping
MCR8DCMT4	DPAK 369A	16mm Tape and Reel (2.5K/Reel)
MCR8DCNT4	DPAK 369A	16mm Tape and Reel (2.5K/Reel)

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance — Junction to Case — Junction to Ambient — Junction to Ambient ⁽¹⁾	R _θ JC R _θ JA R _θ JA	2.2 88 80	°C/W
Maximum Lead Temperature for Soldering Purposes(2)	т	260	°C

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Unit		
OFF CHARACTERISTICS							
$ \begin{array}{l} \mbox{Peak Repetitive Forward or Peak Repetitive Reverse Blocking Current} \\ (V_{AK} = Rated \ V_{DRM} \ or \ V_{RRM}, \ Gate \ Open) \\ T_J = 25^{\circ}C \\ T_J = 125^{\circ}C \end{array} $	IDRM, IRRM			0.01 5.0	mA		
ON CHARACTERISTICS							
Peak On–State Voltage ⁽³⁾ (I _{TM} = 16 A)	VTM	_	1.4	1.8	Volts		
Gate Trigger Current (Continuous dc) $(V_{AK} = 12 \text{ V}, \text{ R}_{L} = 100 \Omega, \text{ T}_{J} = 25^{\circ}\text{C})$ $(\text{T}_{J} = -40^{\circ}\text{C})$	IGT	2.0	7.0	15 30	mA		
Gate Trigger Voltage (Continuous dc) $(V_{AK} = 12 \text{ V}, \text{ R}_{L} = 100 \Omega, \text{ T}_{J} = 25^{\circ}\text{C})$ $(\text{T}_{J} = -40^{\circ}\text{C})$ $(\text{T}_{J} = 125^{\circ}\text{C})$	V _{GT}	0.5 — 0.2	0.65 —	1.0 2.0 —	Volts		
	Ч	4.0	22 —	30 60	mA		
Latching Current (V _{AK} = 12 V, I _G = 15 mA, T _J = 25°C) (V _{AK} = 12 V, I _G = 30 mA, T _J = -40° C)	ι	4.0	22 —	30 60	mA		
DYNAMIC CHARACTERISTICS							
Critical Rate of Rise of Off-State Voltage	dv/dt				V/µs		

Critical Rate of Rise of Off–State Voltage	dv/dt				V/μs
(V _{AK} = Rated V _{DRM} , Exponential Waveform, Gate Open, T_J = 125°C)		50	200	—	

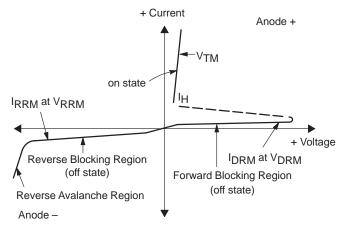
(1) Surface mounted on minimum recommended pad size.

(2) 1/8" from case for 10 seconds.

(3) Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%.

Voltage Current Characteristic of SCR

Parameter
Peak Repetitive Off State Forward Voltage
Peak Forward Blocking Current
Peak Repetitive Off State Reverse Voltage
Peak Reverse Blocking Current
Peak On State Voltage
Holding Current



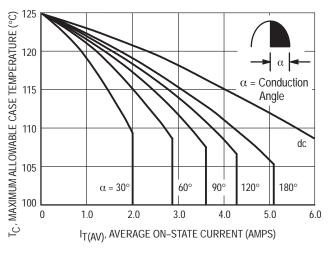


Figure 1. Average Current Derating

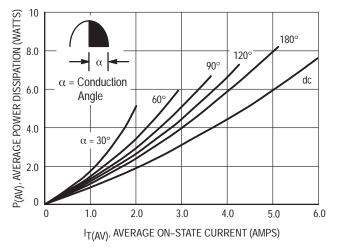


Figure 2. On-State Power Dissipation

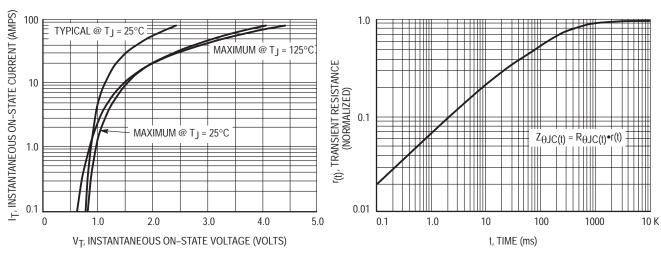


Figure 3. On–State Characteristics



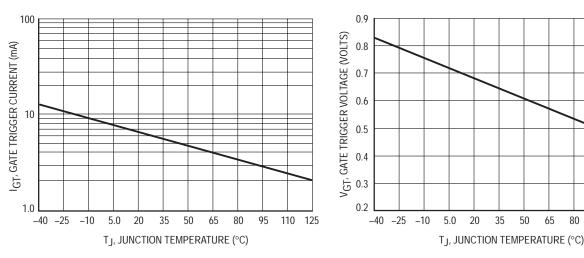


Figure 5. Typical Gate Trigger Current versus Junction Temperature

Figure 6. Typical Gate Trigger Voltage versus Junction Temperature

95

110 125

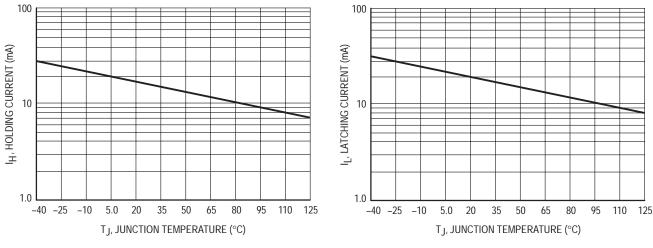
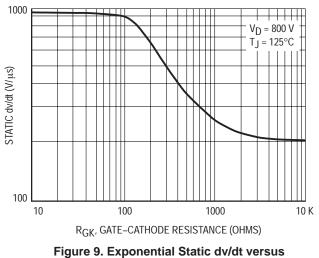


Figure 7. Typical Holding Current versus Junction Temperature



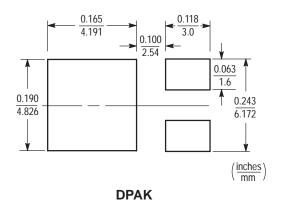


Gate–Cathode Resistance

MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

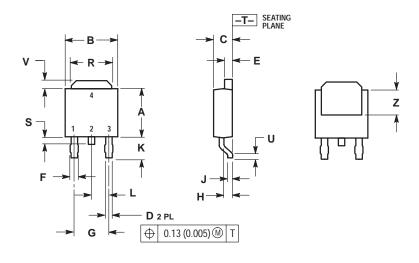
Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



PACKAGE DIMENSIONS

D-PAK CASE 369A-13 ISSUE Z



NOT	'ES:
1.	DIMENSIONING AND TOLERANCING PER ANSI
	Y14.5M, 1982.
2.	CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.250	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
Ε	0.033	0.040	0.84	1.01
F	0.037	0.047	0.94	1.19
G	0.180 BSC		4.58	BSC
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090 BSC		2.29 BSC	
R	0.175	0.215	4.45	5.46
S	0.020	0.050	0.51	1.27
U	0.020		0.51	
٧	0.030	0.050	0.77	1.27
Z	0.138		3.51	

STYLE 4: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE

Notes

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